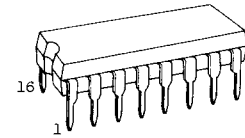


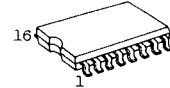
TC4019BP/TC4019BF QUAD AND/OR SELECT GATE

TC4019BP/BF is four circuit AND-OR SELECT GATE. The basic circuit consists of two 2 input AND gates and an OR gate receiving two outputs from the AND gates. The input signals applied to A_n and B_n (n=1~4) are selected by the common selection input to all the four circuits, KA and KB and the outputs are obtained at D_n.

This is suitable for data selectors and multiplexers of 4 bits 2 channels.



DIP16(3D16A-P)

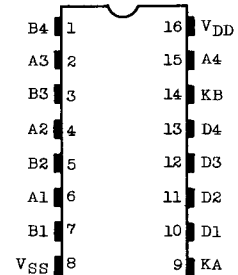


MFP16(F16GC-P)

ABSOLUTE MAXIMUM RATINGS

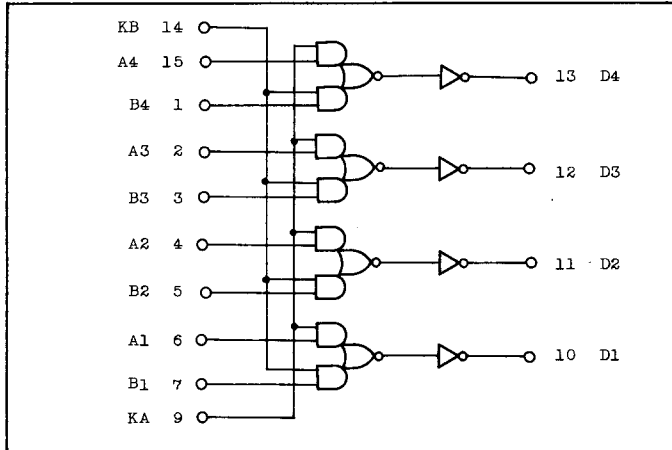
CHARACTERISTIC	SYMBOL	RATING	UNIT
DC Supply Voltage	V _{DD}	V _{SS} - 0.5 ~ V _{SS} + 20	V
Input Voltage	V _{IN}	V _{SS} - 0.5 ~ V _{DD} + 0.5	V
Output Voltage	V _{OUT}	V _{SS} - 0.5 ~ V _{DD} + 0.5	V
DC Input Current	I _{IN}	±10	mA
Power Dissipation	P _D	300(DIP)/180(MFP)	mW
Operating Temperature Range	T _A	-40 ~ 85	°C
Storage Temperature Range	T _{stg}	-65 ~ 150	°C
Lead Temp./Time	T _{sol}	260°C · 10 sec	

PIN ASSIGNMENT



(TOP VIEW)

LOGIC DIAGRAM



TRUTH TABLE

INPUTS				OUTPUT
KA	KB	A _n	B _n	D _n
H	L	H	*	H
H	L	L	*	L
L	H	*	H	H
L	H	*	L	L
L	L	*	*	L
H	H	L	L	L
H	H	L	H	H
H	H	H	L	H
H	H	H	H	H

L : LOW LEVEL
H : HIGH LEVEL
* : DON'T CARE

TC4019BP/BF

RECOMMENDED OPERATING CONDITIONS (V_{SS}=0V)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNITS
DC Supply Voltage	V _{DD}	3	-	18	V
Input Voltage	V _{IN}	0	-	V _{DD}	V

STATIC ELECTRICAL CHARACTERISTICS (V_{SS}=0V)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	V _{DD} (V)	-40°C		25°C			85°C		UNITS
				MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.	
High-Level Output Voltage	V _{OH}	I _{OUT} < 1μA V _{IN} =V _{SS} , V _{DD}	5	4.95	-	4.95	5.00	-	4.95	-	V
			10	9.95	-	9.95	10.00	-	9.95	-	
			15	14.95	-	14.95	15.00	-	14.95	-	
Low-Level Output Voltage	V _{OL}	I _{OUT} < 1μA V _{IN} =V _{SS} , V _{DD}	5	-	0.05	-	0.00	0.05	-	0.05	V
			10	-	0.05	-	0.00	0.05	-	0.05	
			15	-	0.05	-	0.00	0.05	-	0.05	
Output High Current	I _{OH}	V _{OH} =4.6V V _{OH} =2.5V V _{OH} =9.5V V _{OH} =13.5V V _{IN} =V _{SS} , V _{DD}	5	-0.61	-	-0.51	-1.0	-	-0.42	-	mA
			5	-2.5	-	-2.1	-4.0	-	-1.7	-	
			10	-1.5	-	-1.3	-2.2	-	-1.1	-	
			15	-4.0	-	-3.4	-9.0	-	-2.8	-	
Output Low Current	I _{OL}	V _{OL} =0.4V V _{OL} =0.5V V _{OL} =1.5V V _{IN} =V _{SS} , V _{DD}	5	0.61	-	0.51	1.2	-	0.42	-	mA
			10	1.5	-	1.3	3.2	-	1.1	-	
			15	4.0	-	3.4	12.0	-	2.8	-	
			5	3.5	-	3.5	2.75	-	3.5	-	
Input High Voltage	V _{IH}	V _{OUT} =0.5V, 4.5V V _{OUT} =1.0V, 9.0V V _{OUT} =1.5V, 13.5V I _{OUT} < 1μA	5	3.5	-	3.5	2.75	-	3.5	-	V
			10	7.0	-	7.0	5.5	-	7.0	-	
			15	11.0	-	11.0	8.25	-	11.0	-	
			5	-	1.5	-	2.25	1.5	-	1.5	
Input Low Voltage	V _{IL}	V _{OUT} =0.5V, 4.5V V _{OUT} =1.0V, 9.0V V _{OUT} =1.5V, 13.5V I _{OUT} < 1μA	10	-	3.0	-	4.5	3.0	-	3.0	V
			15	-	4.0	-	6.75	4.0	-	4.0	
			5	-	0.1	-	10 ⁻⁵	0.1	-	1.0	
			18	-	-0.1	-	10 ⁻⁵	-0.1	-	-1.0	
Quiescent Device Current	I _{DD}	V _{IN} =V _{SS} , V _{DD} *	5	-	0.25	-	0.001	0.25	-	7.5	μA
			10	-	0.5	-	0.001	0.5	-	15	
			15	-	1.0	-	0.002	1.0	-	30	

* All valid input combinations

DYNAMIC ELECTRICAL CHARACTERISTICS (Ta=25°C, VSS=0V, CL=50pF)

CHARACTERISTIC	SYMBOL	TEST CONDITION	VDD(V)	MIN.	TYP.	MAX.	UNITS
Output Transition Time (Low to High)	t _{TLH}		5	-	70	200	ns
			10	-	35	100	
			15	-	30	80	
Propagation Delay Time (A, B - D)	t _{pLH} t _{pHL}		5	-	75	300	
			10	-	40	120	
			15	-	30	100	
Propagation Delay Time (KA, KB - D)	t _{pLH} t _{pHL}		5	-	75	300	
			10	-	40	120	
			15	-	30	100	
Input Capacitance	C _{IN}	An, Bn Input		-	5	7.5	
		KA, KB Input		-	12	20	

WAVEFORM FOR MEASUREMENT OF DYNAMIC CHARACTERISTICS

